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PATENT

K1.3/Z

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of Ritu Shrivastava et al.

Appln. No. 08/654,615

Filed: May 29, 1996

For: DRAM CELL WITH SELF-ALIGNED) CONTACT AND METHOD OF

FABRICATING SAME

Group Art Unit: 2503

Examiner: H. Tsai

AMENDMENT AFTER NOTICE OF ALLOWANCE PURSUANT TO 37 C.F.R. §1.312(a)

2001 Ferry Building San Francisco, CA 94111 (415) 433-4150 CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail Assistant Commissioner for Patentis an envelope address to: Assistant Commissioner for Patents, Washington, DC 20231

Washington, D.C. 20231

Sir:

It is requested that the above-identified application be amended as follows:

IN THE CLAIMS

In claim 6, line 21, after "dielectric", please change "materials" to --material -- .

REMARKS

A Notice of Allowance was issued in the aboveidentified application on January 29, 1997.

Upon review of the allowed claims in this application, applicants have discovered an inadvertent typographical error in claim 6, which it is proposed be amended as indicated above.

Since the proposed amendment is directed to formal matters in an allowed claim without changing the scope thereof, it is requested that the proposed It is believed that no amendment be entered. substantial amount of additional work on the part of